NSN 5961-01-214-5675

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-214-5675 **Inclosure Material:** Metal **Overall Length:** 1.150 inches **Terminal Length:** 0.360 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** 0.034 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 25.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 unthreaded hole Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Eiid

Fiig:

A110a0